

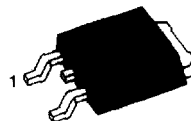
HIGH VOLTAGE POWER TRANSISTOR D-PAK FOR SURFACE MOUNT APPLICATIONS

- High speed Switching
- Suitable for Switching Regulator Motor Control
- Straight Lead(I.PACK, I Suffix)
- Lead Formed for Surface Mount Applications(No Suffix)

ABSOLUTE MAXIMUM RATINGS

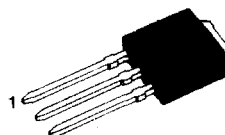
Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V_{CBO}	700	V
Collector-Emitter Voltage	V_{CEO}	400	V
Emitter-Base Voltage	V_{EBO}	9	V
Collector Current (DC)	I_C	1.5	A
Collector Current (Pulse)	I_C	3	A
Base Current	I_B	0.75	A
Collector Dissipation ($T_C=25^\circ\text{C}$)	P_C	40	W
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-65 ~ 150	$^\circ\text{C}$

D-PAK



1. Base 2. Collector 3. Emitter

I-PAK



1. Base 2. Collector 3. Emitter

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
* Collector Emitter Breakdown Voltage	$V_{CEO(sus)}$	$I_C = 5\text{mA}, I_B = 0$	400			V
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 9\text{V}, I_C = 0$			10	μA
* DC Current Gain	h_{FE}	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$	8		40	
		$V_{CE} = 1\text{V}, I_C = 2\text{A}$	5			
* Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 0.5\text{A}, I_B = 0.1\text{A}$			0.5	V
		$I_C = 1\text{A}, I_B = 0.25\text{A}$			1	V
		$I_C = 1.5\text{A}, I_B = 0.5\text{A}$			3	V
* Base Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 0.5\text{A}, I_B = 0.1\text{A}$			1	V
		$I_C = 1\text{A}, I_B = 0.25\text{A}$			1.2	V
Output Capacitance	C_{OB}	$V_{CB} = 10\text{V}, f = 0.1\text{MHz}$		21		pF
Current - Gain Bandwidth Product	f_T	$V_{CE} = 10\text{V}, I_C = 0.1\text{A}$	4			MHz
Turn on time	t_{ON}	$V_{CC} = 125\text{V}$			1.1	μs
Storage time	t_{STG}	$I_C = 1\text{A}$			4.0	μs
Fall Time	t_F	$I_{B1} = 0.2\text{A}, I_{B2} = -0.2\text{A}$			0.7	μs

* Pulse Test : Pulse Width=5ms, Duty Cycle $\leq 10\%$

